

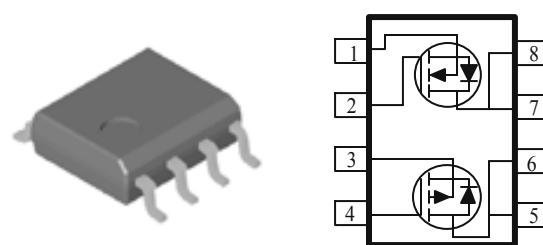
P & N-Channel 30-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize High Cell Density process. Low $r_{DS(on)}$ assures minimal power loss and conserves energy, making this device ideal for use in power management circuitry. Typical applications are PWMDC-DC converters, power management in portable and battery-powered products such as computers, printers, battery charger, telecommunication power system, and telephones power system.

- Low $r_{DS(on)}$ Provides Higher Efficiency and Extends Battery Life
- Miniature SO-8 Surface Mount Package Saves Board Space
- High power and current handling capability
- Low side high current DC-DC Converter applications

PRODUCT SUMMARY

| V_{DS} (V) | $r_{DS(on)}$ m(Ω) | I_D (A) |
|--------------|----------------------------|-----------|
| 30 | 40 @ $V_{GS} = 4.5V$ | 6.0 |
| | 31 @ $V_{GS} = 10V$ | 6.9 |
| -30 | 80 @ $V_{GS} = -4.5V$ | -4.2 |
| | 52 @ $V_{GS} = -10V$ | -5.2 |



ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ C$ UNLESS OTHERWISE NOTED)

| Parameter | Symbol | N-Channel | P-Channel | Units |
|---|----------------|------------|-----------|-------|
| Drain-Source Voltage | V_{DS} | 30 | -30 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | ± 20 | |
| Continuous Drain Current ^a | I_D | 6.9 | -5.2 | A |
| | | 5.4 | -6.8 | |
| Pulsed Drain Current ^b | I_{DM} | 20 | -20 | |
| Continuous Source Current (Diode Conduction) ^a | I_S | 1.3 | -1.3 | A |
| Power Dissipation ^a | P_D | 2.1 | 2.1 | W |
| | | 1.3 | 1.3 | |
| Operating Junction and Storage Temperature Range | T_J, T_{stg} | -55 to 150 | | °C |

THERMAL RESISTANCE RATINGS

| Parameter | Symbol | Maximum | Units |
|--|-----------------|---------|-------|
| Maximum Junction-to-Case ^a | $R_{\theta JC}$ | 40 | °C/W |
| Maximum Junction-to-Ambient ^a | $R_{\theta JA}$ | 60 | °C/W |

Notes

- Surface Mounted on 1" x 1" FR4 Board.
- Pulse width limited by maximum junction temperature

SPECIFICATIONS ($T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)

| Parameter | Symbol | Test Conditions | Limits | | | | Unit |
|---|---------------------|---|--------|------|------|-----------|------|
| | | | Ch | Min | Typ | Max | |
| Static | | | | | | | |
| Gate-Threshold Voltage | $V_{GS(\text{th})}$ | $V_{GS} = V_{DS}, I_D = 250 \mu\text{A}$ | N | 1 | | | V |
| | | $V_{GS} = V_{DS}, I_D = -250 \mu\text{A}$ | P | -1.0 | | | |
| Gate-Body Leakage | I_{GSS} | $V_{GS} = -20 \text{ V}, V_{DS} = 0 \text{ V}$ | P | | | ± 100 | nA |
| | | $V_{GS} = 20 \text{ V}, V_{DS} = 0 \text{ V}$ | N | | | ± 100 | |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}$ | P | | | -1 | uA |
| | | $V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$ | N | | | 1 | |
| On-State Drain Current ^A | $I_{D(\text{on})}$ | $V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$ | N | 20 | | | A |
| | | $V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$ | P | -20 | | | |
| Drain-Source On-Resistance ^A | $r_{DS(\text{on})}$ | $V_{GS} = 10 \text{ V}, I_D = 6.9 \text{ A}$ | N | | | 31 | mΩ |
| | | $V_{GS} = 4.5 \text{ V}, I_D = 6 \text{ A}$ | | | | 40 | |
| | | $V_{GS} = -10 \text{ V}, I_D = -5.2 \text{ A}$ | P | | | 52 | |
| | | $V_{GS} = -4.5 \text{ V}, I_D = -4.2 \text{ A}$ | | | | 80 | |
| Forward Transconductance ^A | g_{fs} | $V_{DS} = 15 \text{ V}, I_D = 6.9 \text{ A}$ | N | | 25 | | S |
| | | $V_{DS} = -15 \text{ V}, I_D = -5.2 \text{ A}$ | P | | 10 | | |
| Dynamic | | | | | | | |
| Total Gate Charge | Q_g | N-Channel $V_{DS}=15\text{V}, V_{GS}=10\text{V}, I_D=6.9\text{A}$ P-Channel $V_{DS}=-15\text{V}, V_{GS}=-10\text{V}, I_D=-5.2\text{A}$ | N | | 4.0 | | nC |
| Gate-Source Charge | Q_{gs} | | P | | 10 | | |
| Gate-Drain Charge | Q_{gd} | | N | | 1.1 | | |
| Turn-On Delay Time | $t_{d(\text{on})}$ | | P | | 2.2 | | |
| Rise Time | t_r | | N | | 1.4 | | |
| Turn-Off Delay Time | $t_{d(\text{off})}$ | | P | | 1.7 | | |
| Fall-Time | t_f | | N | | 8 | | nS |
| | | | P | | 10 | | |
| | | N-Channel $V_{DD}=15\text{V}, V_{GS}=10\text{V}, I_D=1\text{A}$, $R_{GEN}=6\Omega$, P-Channel $V_{DD}=-15\text{V}, V_{GS}=-10\text{V}, I_D=-1\text{A}$, $R_{GEN}=6\Omega$ | N | | 5 | | |
| | | | P | | 2.8 | | |
| | | | N | | 23 | | |
| | | | P | | 53.6 | | |
| | | | N | | 3 | | |
| | | | P | | 46 | | |

Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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Typical Electrical Characteristics (N-Channel)

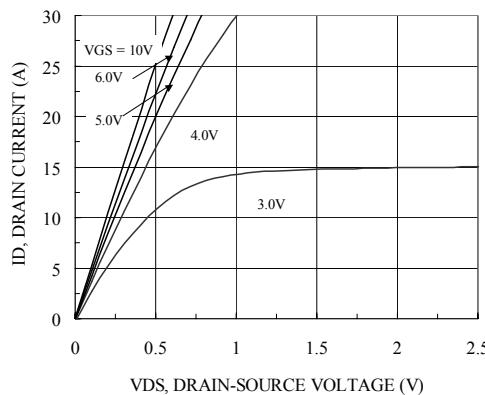


Figure 1. On-Region Characteristics

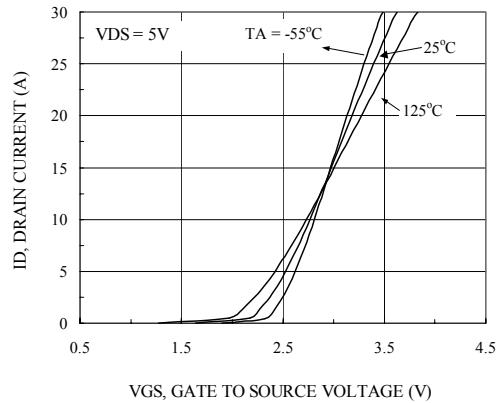


Figure 2. Body Diode Forward Voltage Variation with Source Current and Temperature

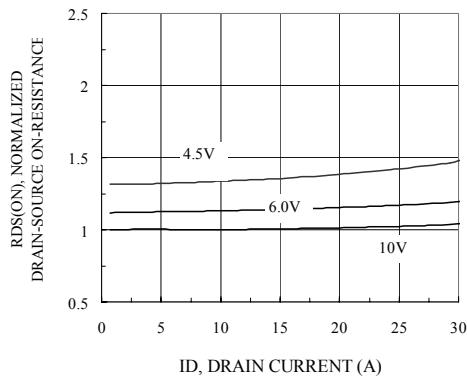


Figure 3. On Resistance Vs Vgs Voltage

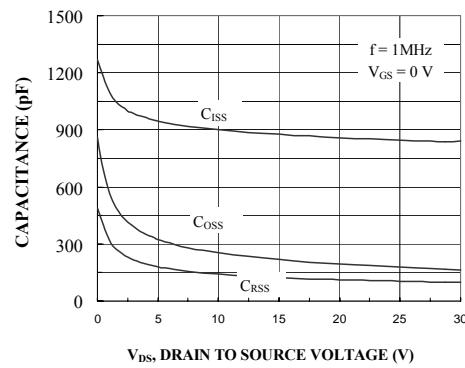


Figure 4. Capacitance Characteristics

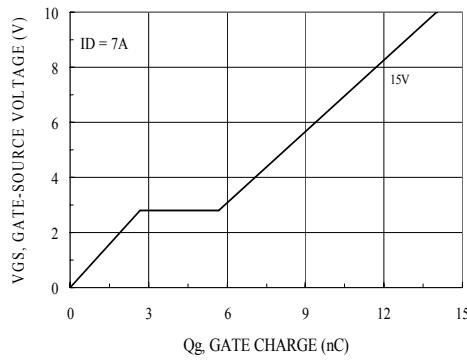


Figure 5. Gate Charge Characteristics

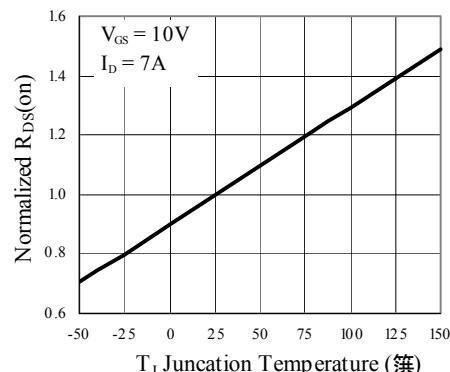


Figure 6. On-Resistance Variation with Temperature

Typical Electrical Characteristics (N-Channel)

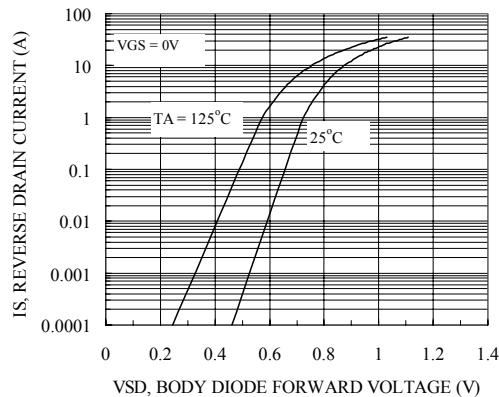


Figure 7. Transfer Characteristics

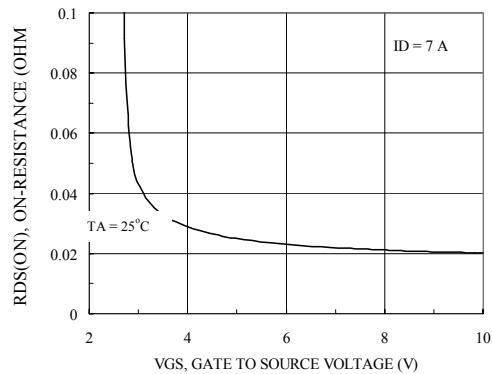


Figure 8. On-Resistance with Gate to Source Voltage

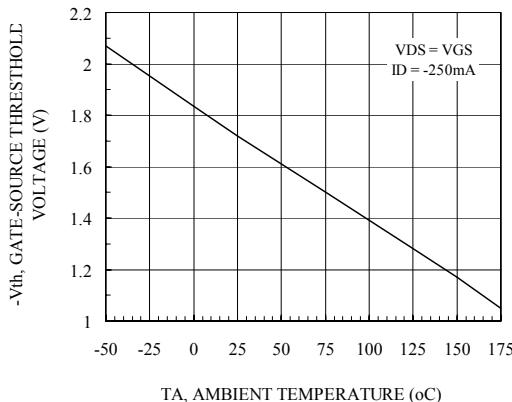


Figure 9. V_{th} Gate to Source Voltage Vs Temperature

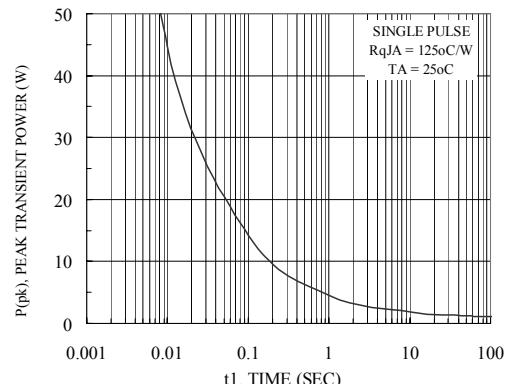


Figure 10. Single Pulse Maximum Power Dissipation

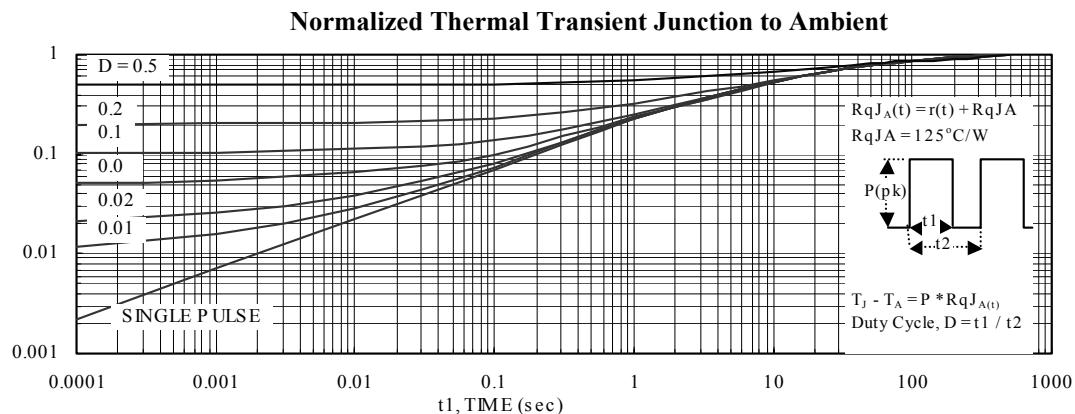


Figure 11. Transient Thermal Response Curve

Typical Electrical Characteristics (P-Channel)

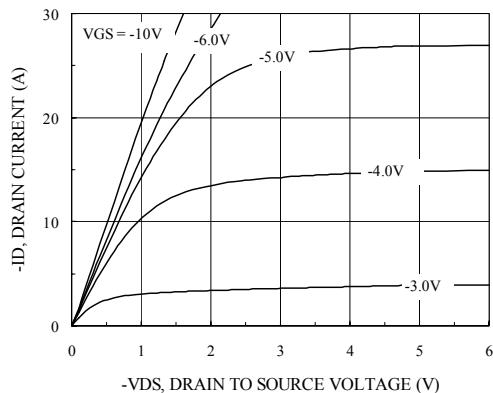


Figure 1. On-Region Characteristics

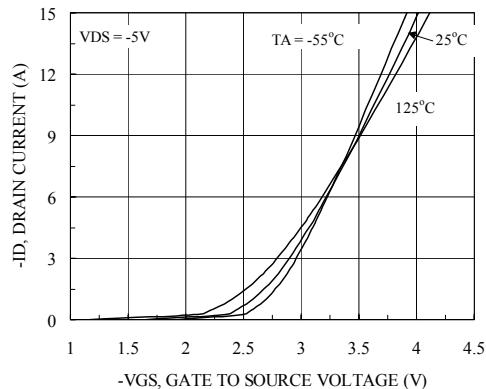


Figure 2. Body Diode Forward Voltage Variation with Source Current and Temperature

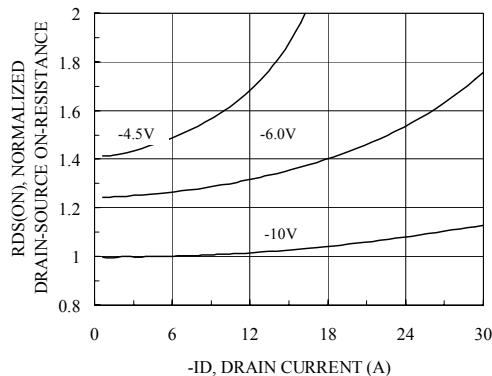


Figure 3. On Resistance Vs Vgs Voltage

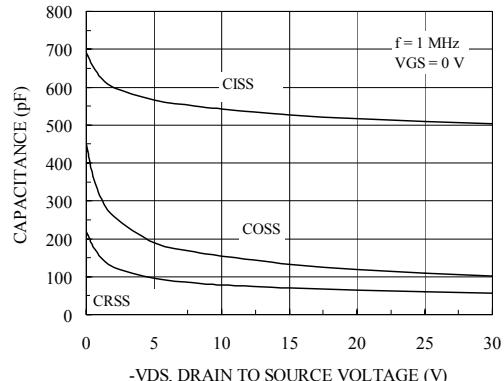


Figure 4. Capacitance Characteristics

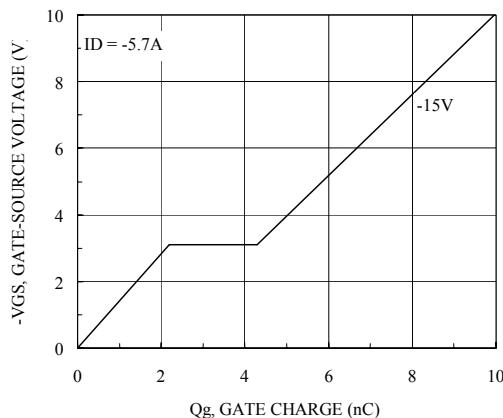


Figure 5. Gate Charge Characteristics

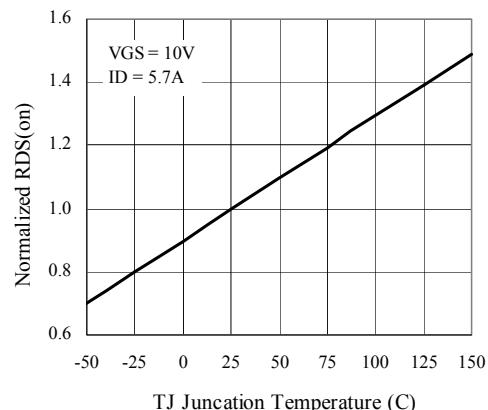


Figure 6. On-Resistance Variation with Temperature

Typical Electrical Characteristics (P-Channel)

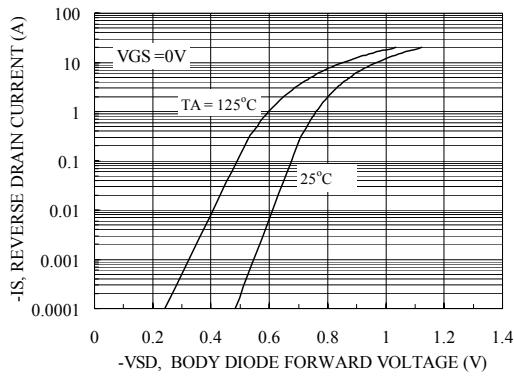


Figure 7. Transfer Characteristics

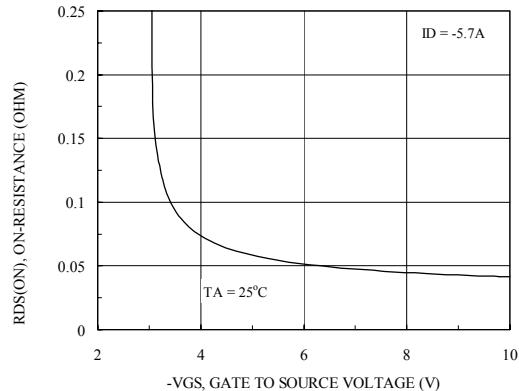


Figure 8. On-Resistance with Gate to Source Voltage

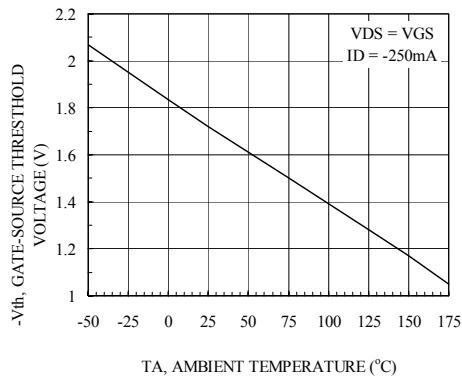


Figure 9. Vth Gate to Source Voltage Vs Temperature

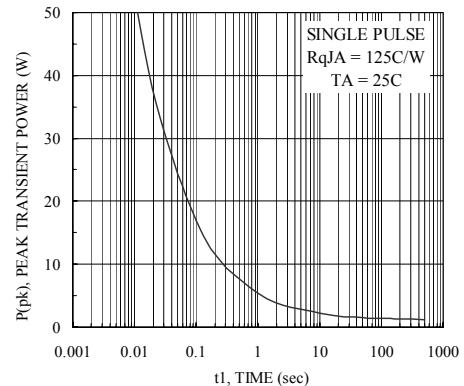


Figure 10. Single Pulse Maximum Power Dissipation

Normalized Thermal Transient Junction to Ambient

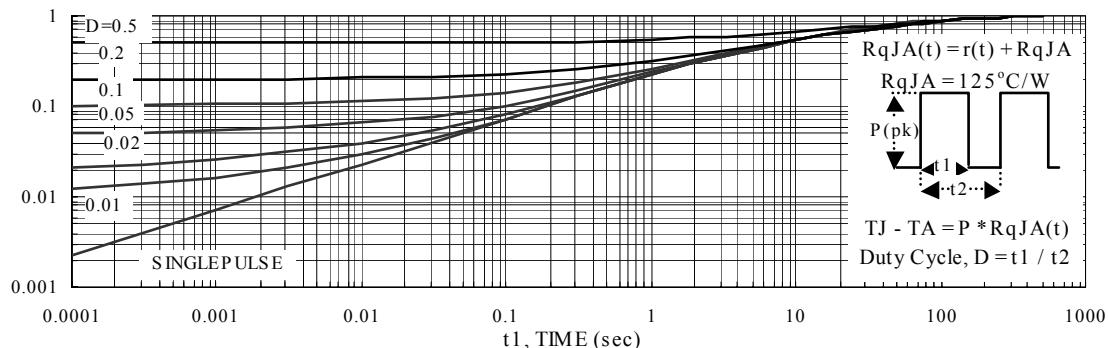
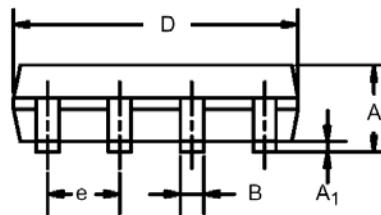
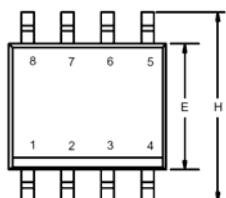


Figure 11. Transient Thermal Response Curve

Package Information

SO-8: 8LEAD



| Dim | MILLIMETERS | | INCHES | |
|----------------|-------------|------|-----------|-------|
| | Min | Max | Min | Max |
| A | 1.35 | 1.75 | 0.053 | 0.069 |
| A ₁ | 0.10 | 0.20 | 0.004 | 0.008 |
| B | 0.35 | 0.51 | 0.014 | 0.020 |
| C | 0.19 | 0.25 | 0.0075 | 0.010 |
| D | 4.80 | 5.00 | 0.189 | 0.196 |
| E | 3.80 | 4.00 | 0.150 | 0.157 |
| e | 1.27 BSC | | 0.050 BSC | |
| H | 5.80 | 6.20 | 0.228 | 0.244 |
| h | 0.25 | 0.50 | 0.010 | 0.020 |
| L | 0.50 | 0.93 | 0.020 | 0.037 |
| q | 0° | 8° | 0° | 8° |

